

CMOS Digital Integrated Circuits Silicon Monolithic

74HC574D

1. Functional Description

· Octal D-Type Flip Flop with 3-State Outputs

2. General

The 74HC574D is a high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type flip-flops are controlled by a clock input (CK) and an output enable input (OE).

When the OE input is high, the eight outputs are in a high impedance state.

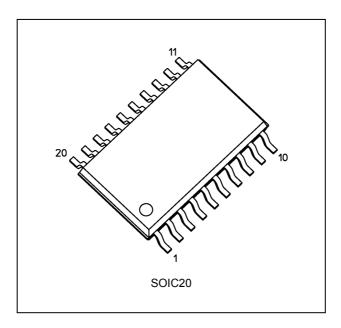
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: $f_{MAX} = 59 \text{ MHz}$ (typ.) at $V_{CC} = 6.0 \text{ V}$
- (3) Low power dissipation: $I_{CC} = 4.0 \,\mu\text{A}$ (max) at $T_a = 25 \,^{\circ}\text{C}$
- (4) Balanced propagation delays: t_{PLH} ≈ t_{PHL}
- (5) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 6.0 V

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

4. Packaging

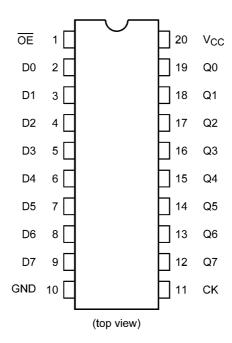


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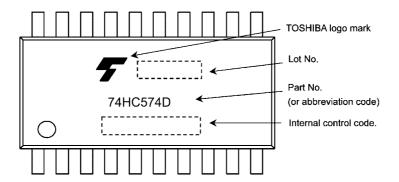
Start of commercial production



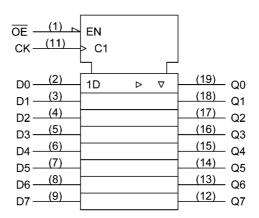
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



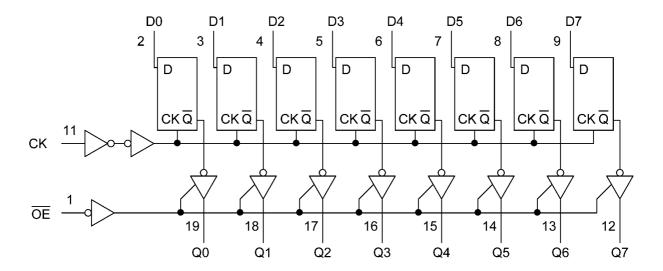


8. Truth Table

	Inputs		Output
ŌĒ	СК	D	Output
Н	Х	Х	Z
L	□	Х	Qn
L		L	L
L		Н	Н

X: Don't careZ: High impedanceQn: No change

9. System Diagram





10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±35	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P _D	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

11. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}			2.0 to 6.0	V
Input voltage	V _{IN}			0 to V _{CC}	V
Output voltage	V _{OUT}			0 to V _{CC}	V
Operating temperature	T _{opr}	(Note 1)		-40 to 125	°C
Input rise and fall times	t _r ,t _f		V _{CC} = 2.0 V	0 to 1000	ns
			V _{CC} = 4.5 V	0 to 500	
			V _{CC} = 6.0 V	0 to 400	
		(Note 1)		0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

Rev.3.0



12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				4.5	3.15	_	_]
				6.0	4.20	_	_	
Low-level input voltage	V _{IL}	_		2.0	_	_	0.50	V
				4.5	_	_	1.35	
					_	_	1.80	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	_	V
				4.5	4.4	4.5	_	
				6.0	5.9	6.0	_	
			I_{OH} = -6 mA	4.5	4.18	4.31	_	
			I_{OH} = -7.8 mA	6.0	5.68	5.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0		0.0	0.1	V
				4.5	_	0.0	0.1	
				6.0	_	0.0	0.1	
			I _{OL} = 6 mA	4.5	_	0.17	0.26	
			I _{OL} = 7.8 mA	6.0	_	0.18	0.26	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_		±0.5	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND	_	6.0	_	_	±0.1	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		6.0	_	_	4.0	μА

12.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	١	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	
Low-level input voltage	V _{IL}	_		2.0		0.50	V
				4.5		1.35	
						1.80	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I_{OH} = -6 mA	4.5	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.63	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 20 μA	2.0		0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I_{OL} = 6 mA	4.5	_	0.33	
			I _{OL} = 7.8 mA	6.0	_	0.33	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0		±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		6.0		40.0	μА



12.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	า	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_]
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				4.5	_	1.35	
				6.0	_	1.80]
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_]
			I _{OH} = -6 mA	4.5	3.7	_	
			I _{OH} = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I _{OL} = 6 mA	4.5	_	0.4]
			I _{OL} = 7.8 mA	6.0	_	0.4	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	_	80.0	μА

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



12.4. Timing Requirements (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	2.0	_	75	ns
(CK)			4.5	_	15]
			6.0	_	13	
Minimum setup time (Dn)	t _s	_	2.0	_	75	ns
			4.5	_	15	
			6.0	_	13	
Minimum hold time	t _h	_	2.0	_	0	ns
(Dn)			4.5	_	0	
			6.0	_	0	
Clock frequency	f		2.0	_	6	MHz
			4.5	_	31	
			6.0	_	36	

12.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	2.0	95	ns
(CK)			4.5	19	
			6.0	16	
Minimum setup time (Dn)	ts	_	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum hold time	t _h	_	2.0	0	ns
(Dn)			4.5	0	
			6.0	0	
Clock frequency	f	_	2.0	5	MHz
			4.5	24	
			6.0	28	

12.6. Timing Requirements (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	2.0	108	ns
(CK)			4.5	22	
			6.0	18	
Minimum setup time	t _s	_	2.0	108	ns
(Dn)			4.5	22	
			6.0	18	
Minimum hold time	t _h	_	2.0	0	ns
(Dn)			4.5	0	
			6.0	0	
Clock frequency	f	_	2.0	4	MHz
			4.5	19	
			6.0	23	

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		_	50	2.0	_	25	60	ns
					4.5	_	7	12	
					6.0	_	6	10	
Propagation delay time	t _{PLH} ,t _{PHL}		_	50	2.0		70	150	ns
(CK-Q)					4.5	_	20	30	
					6.0	_	15	26	
				150	2.0	_	88	190	
					4.5	_	25	38	
					6.0	-	19	33	
Output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	50	2.0	_	48	125	ns
					4.5	_	15	25	.
					6.0	_	12	21	
				150	2.0	_	60	165	
					4.5	_	20	33	
					6.0	_	16	28	
Output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	50	2.0	_	34	125	ns
					4.5	_	17	25	
					6.0		15	21	
Maximum clock frequency	f _{MAX}		_	50	2.0	6	17	_	MHz
					4.5	31	50	_	
					6.0	36	59	_	
Input capacitance	C _{IN}		_			_	5	10	pF
Output capacitance	C _{OUT}		_			_	10	_	pF
Power dissipation capacitance	C _{PD}	(Note 1)	_			_	54	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs of latch operate can be gained by the following equation.

 C_{PD} (total) = 39 + 15 × n



12.8. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	_	50	2.0	_	75	ns
				4.5	_	15	
				6.0	_	13	
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0		190	ns
(CK-Q)				4.5		38	
				6.0		33	
			150	2.0		240	
				4.5		48	
				6.0		41	
Output enable time	t_{PZL}, t_{PZH}	R _L = 1 kΩ	50	2.0		155	ns
				4.5		31	
				6.0		26	
			150	2.0		205	
				4.5		41	
				6.0		35	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	2.0		155	ns
				4.5		31	
				6.0		26	
Maximum clock frequency	f _{MAX}	_	50	2.0	5	_	MHz
				4.5	24	_	
				6.0	28	_	
Input capacitance	C _{IN}	_				10	pF



12.9. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

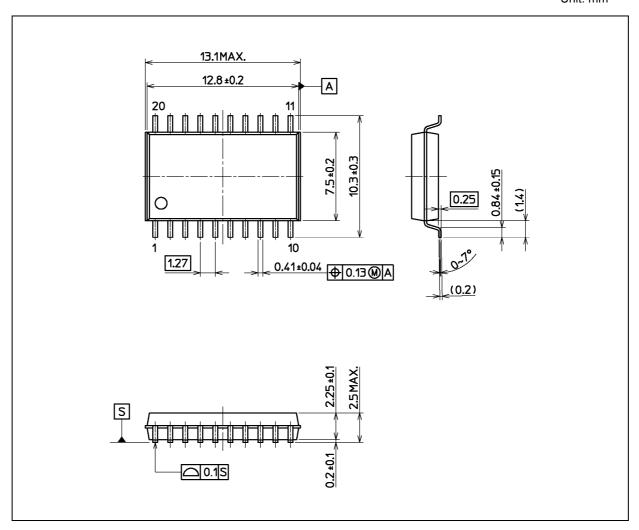
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	_	2.0	50		85	ns
			4.5			17	
			6.0]	_	15	1
Propagation delay time	t _{PLH} ,t _{PHL}	_	2.0	50	_	217	ns
(CK-Q)			4.5			43	
			6.0		_	38	
			2.0	150		273	
			4.5			55	
			6.0		_	46	
Output enable time	t_{PZL}, t_{PZH}	$R_L = 1 k\Omega$	2.0	50	_	175	ns
			4.5			35	
			6.0		_	29	
			2.0	150		232	
			4.5			46	
			6.0			40	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	2.0	50		175	ns
			4.5			35	
			6.0		_	29	
Maximum clock frequency	f _{MAX}	_	2.0	50	4		MHz
			4.5		19]
			6.0		23		
Input capacitance	C _{IN}	_			_	10	pF

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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